Datasheet

2.7 V to 5.5 V Input, 600 mA Single Synchronous Buck DC/DC Converter for Automotive

BD9SD11NUX-C

General Description

BD9SD11NUX-C is a synchronous buck DC/DC Converter with built-in low On Resistance power MOSFETs. It is capable of providing current up to 600 mA. Small inductor is applicable due to high switching frequency of 2.2 MHz. It is a current mode control DC/DC Converter and features high-speed transient response. It has an integrated feedback resistor that sets the output voltage to 1.15 V and a built-in phase compensation circuit. Applications can be created with a few external components.

Features

- AEC-Q100 Qualified *(Note 1)*
- Single Synchronous Buck DC/DC Converter
- Adjustable Soft Start Function
- Power Good Output
- Input Under Voltage Lockout Protection (UVLO)
- Short Circuit Protection (SCP)
- Output Over Voltage Protection (OVP)
- Over Current Protection (OCP)
- Thermal Shutdown Protection (TSD)

(Note 1) Grade 1

Applications

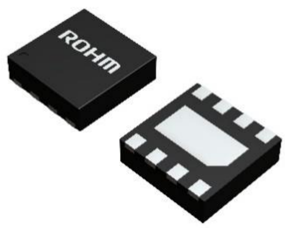
- Automotive Equipment
- Other Electronic Equipment

Key Specifications

Input Voltage:	2.7 V to 5.5 V
Output Voltage:	1.15 V (Typ)
Output Current:	600 mA (Max)
Switching Frequency:	2.2 MHz (Typ)
High Side FET ON Resistance:	270 mΩ (Typ)
Low Side FET ON Resistance:	180 mΩ (Typ)
Shutdown Circuit Current:	0 µA (Typ)
Operating Temperature:	-40 °C to +125 °C

Package

Package	W (Typ) x D (Typ) x H (Max)
VSON008X2020	2.00 mm x 2.00 mm x 0.60 mm



Typical Application Circuit

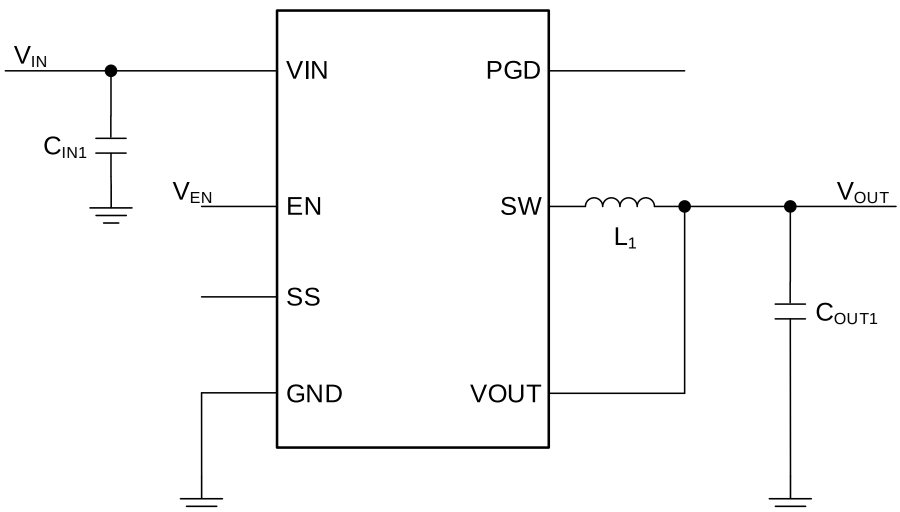
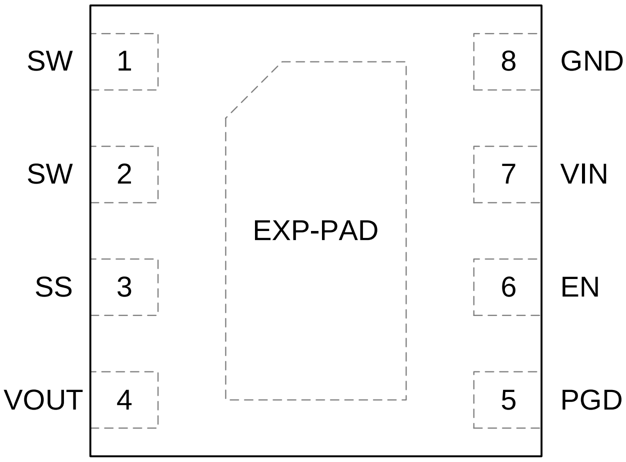


Figure 1. Application Circuit

○Product structure : Silicon integrated circuit ○This product has no designed protection against radioactive rays

Pin Configuration



(TOP VIEW)

Pin Descriptions

Pin No.	Pin Name	Function
1, 2	SW	Switch pin. These pins are connected to the drain of the High Side FET and the Low Side FET.
3	SS	Pin for setting the soft start time. The rise time of the output voltage can be specified by connecting a capacitor to this pin. See page 18 for how to calculate the capacitance.
4	VOUT	V_{OUT} feedback pin. Connect to output voltage sense point.
5	PGD	Power Good pin, an open drain output. It is need to be pulled up to the power supply with a resistor. See page 12 for setting the resistance.
6	EN	Enable pin of the device. Turning this pin Low forces the device to enter the shutdown mode. Turning this pin High makes the device to start up.
7	VIN	Power supply pin. Connecting a 10 µF (Typ) ceramic capacitor is recommended. The detail of a selection is described in page 16.
8	GND	Ground pin.
-	EXP-PAD	A backside heat dissipation pad. Connecting to the internal PCB ground plane by using via provides excellent heat dissipation characteristics.

Block Diagram

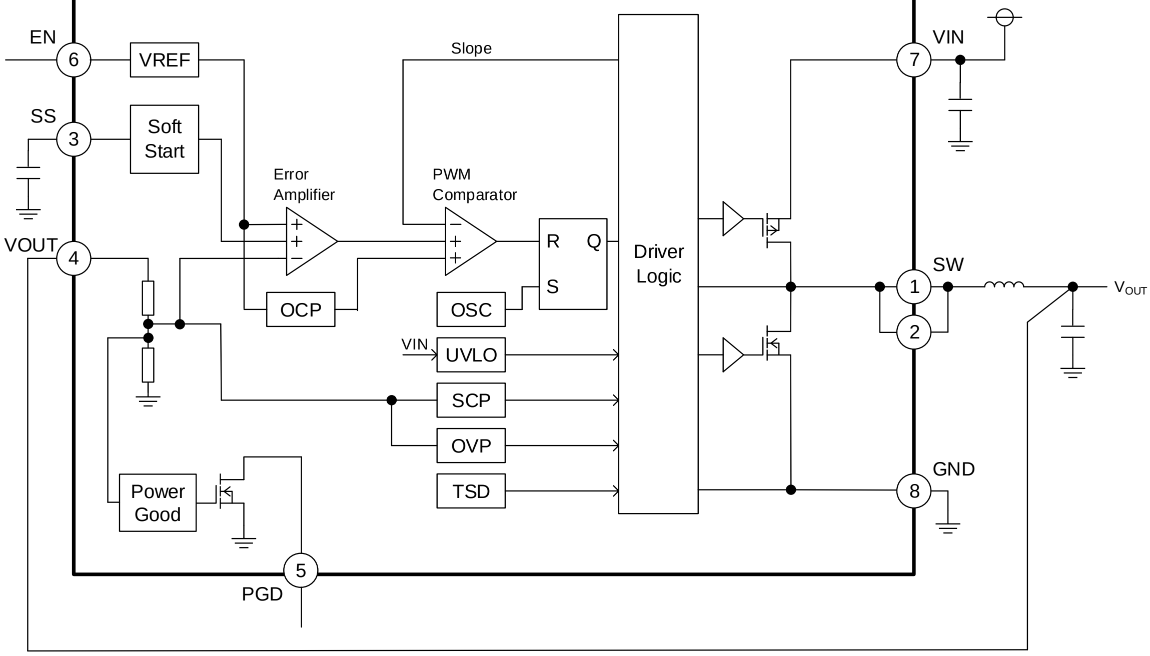


Figure 2. Block Diagram

Description of Blocks

1. VREF
   The VREF block generates the internal reference voltage.

2. UVLO (Under Voltage Lockout)
   The UVLO block is for under voltage lockout protection. It shuts down the device when the V_{IN} falls to 2.45 V (Typ) or lower. The threshold voltage has a hysteresis of 100 mV (Typ).

3. SCP (Short Circuit Protection)
   This is the short circuit protection circuit. After soft start is judged to be completed, if the VOUT pin voltage falls to 70 % (Typ) of the voltage setting or less and remain in that state for 1 ms (Typ), output MOSFETs turn OFF for 14 ms (Typ) and then restart the operation.

4. OVP (Over Voltage Protection)
   This is the output over voltage protection circuit. When the VOUT pin voltage becomes +15 % (Typ) of the voltage setting or more, it turns the output MOSFETs OFF. After output voltage falls +10 % (Typ) of the voltage setting or less, the output MOSFETs returns to normal operation.

5. TSD (Thermal Shutdown)
   This is the thermal shutdown circuit. It shuts down the device when the junction temperature (Tj) reaches to 175 °C (Typ) or more. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation with hysteresis of 25 °C (Typ).

6. OCP (Over Current Protection)
   The Over Current Protection function operates by limiting the current that flows through High Side FET at each cycle of the switching frequency.

7. Soft Start
   The Soft Start circuit slows down the rise of output voltage during startup, which allows the prevention of output voltage overshoot. The soft start time of the output voltage can be specified by connecting a capacitor to the SS pin. See page 18 for how to calculate the capacitance. A built-in soft start function is provided the soft start with Soft Start Time t_{SS} (Refer to page 6) when the SS pin is open.

8. Error Amplifier
   The Error Amplifier block is an error amplifier and its inputs are the reference voltage and the VOUT pin voltage.

9. PWM Comparator
   The PWM Comparator block compares the output voltage of the Error Amplifier and the Slope signal to determine the output switching pulse duty.

10. OSC (Oscillator)
    This block generates the oscillating frequency.

11. Driver Logic
    This block controls switching operation and various protection functions.

12. Power Good
    When the VOUT pin voltage reaches within ±10 % (Typ) of the setting voltage, the built-in Nch MOSFET turns OFF and the PGD output turns high. There is a 5 % hysteresis on the threshold voltage, so the PGD output turns low when the VOUT pin voltage reaches outside ±15 % (Typ) of the voltage setting. This function is enabled after soft start is completed.

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Input Voltage	V_{IN}	-0.3 to +7	V
EN Voltage	V_{EN}	-0.3 to V_{IN}	V
PGD Voltage	V_{PGD}	-0.3 to +7	V
VOUT, SS Voltage	V_{OUT}, V_{SS}	-0.3 to V_{IN}	V
Maximum Junction Temperature	Tjmax	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Caution 1: *Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.*
Caution 2: *Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.*

Thermal Resistance *(Note 1)*

Parameter	Symbol	Thermal Resistance (Typ)		Unit
		1s *(Note 3)*	2s2p *(Note 4)*	
VSON008X2020				
Junction to Ambient	θ_{JA}	309.5	77.1	°C/W
Junction to Top Characterization Parameter *(Note 2)*	Ψ_{JT}	53	12	°C/W

(Note 1) Based on JESD51-2A (Still-Air).
(Note 2) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.
(Note 3) Using a PCB board based on JESD51-3.
(Note 4) Using a PCB board based on JESD51-5, 7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt

Top	
Copper Pattern	Thickness
Footprints and Traces	70 µm

Layer Number of Measurement Board	Material	Board Size	Thermal Via *(Note 5)*	
			Pitch	Diameter
4 Layers	FR-4	114.3 mm x 76.2 mm x 1.6 mmt	1.20 mm	Φ0.30 mm

Top		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	70 µm

(Note 5) This thermal via connects with the copper pattern of all layers.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Input Voltage	V_{IN}	2.7	5.5	V
Operating Temperature	Ta	-40	+125	°C
Output Current	I_{OUT}	-	600	mA

Electrical Characteristics (Unless otherwise specified Ta = Tj = -40 °C to +125 °C, V_{IN} = 5.0 V, V_{EN} = 5.0 V, the typical value is defined at Ta = Tj = +25 °C)

Parameter	Symbol	Limit Min	Limit Typ	Limit Max	Unit	Conditions
VIN						
Shutdown Circuit Current	I_{SDN}	-	0	10	µA	V_{EN} = 0 V, Ta = 25 °C
Circuit Current	I_{CC}	250	400	550	µA	I_{OUT} = 0 mA Non-switching, Ta = 25 °C
UVLO Detection Voltage	V_{UVLO1}	2.30	2.45	2.60	V	V_{IN} Falling
UVLO Release Voltage	V_{UVLO2}	2.40	2.55	2.70	V	V_{IN} Rising
UVLO Hysteresis Voltage	$V_{UVLO\text{-}HYS}$	50	100	125	mV	
ENABLE						
EN Threshold Voltage High	V_{ENH}	1.0	-	V_{IN}	V	
EN Threshold Voltage Low	V_{ENL}	GND	-	0.4	V	
EN Input Current	I_{EN}	2.0	5.0	8.0	µA	V_{EN} = 5.0 V
Output Voltage						
Output Voltage	V_{OUT}	1.133	1.150	1.167	V	V_{IN} = 2.7 V to 5.5 V, *(Note 1)*
VOUT Input Current 1	I_{OUT1}	9.3	14.5	23.2	µA	V_{OUT} = 1.15 V
VOUT Input Current 2	I_{OUT2}	10.4	14.5	18.6	µA	V_{OUT} = 1.15 V, Ta = 25 °C
Soft Start						
Soft Start Time	t_{SS}	0.5	1.0	2.0	ms	V_{IN} = 5.0 V, The SS Pin OPEN
		0.6	1.2	2.4	ms	V_{IN} = 3.3 V, The SS Pin OPEN
SS Charge Current	I_{SS}	-1.4	-1.0	-0.6	µA	
Switching Frequency						
Switching Frequency	f_{SW}	2.0	2.2	2.4	MHz	
Power Good						
PGD Falling (Fault) Voltage	V_{PGDTH_FF}	V_{OUT} x 0.80	V_{OUT} x 0.85	V_{OUT} x 0.90	V	V_{OUT} Falling
PGD Rising (Good) Voltage	V_{PGDTH_RG}	V_{OUT} x 0.85	V_{OUT} x 0.90	V_{OUT} x 0.95	V	V_{OUT} Rising
PGD Rising (Fault) Voltage	V_{PGDTH_RF}	V_{OUT} x 1.10	V_{OUT} x 1.15	V_{OUT} x 1.20	V	V_{OUT} Rising
PGD Falling (Good) Voltage	V_{PGDTH_FG}	V_{OUT} x 1.05	V_{OUT} x 1.10	V_{OUT} x 1.15	V	V_{OUT} Falling
PGD Output Leakage Current	$I_{LEAKPGD}$	-	0	2.0	µA	V_{PGD} = 5.0 V
PGD FET ON Resistance	R_{PGD}	30	60	120	Ω	
PGD Output Low Level Voltage	V_{PGDL}	0.03	0.06	0.12	V	I_{PGD} = 1.0 mA
Switch MOSFET						
High Side FET ON Resistance	R_{ONH}	120	270	470	mΩ	V_{IN} = 5.0 V
		150	330	550	mΩ	V_{IN} = 3.3 V
Low Side FET ON Resistance	R_{ONL}	80	180	300	mΩ	V_{IN} = 5.0 V
		100	210	350	mΩ	V_{IN} = 3.3 V
High Side FET Leakage Current	$I_{LEAKSWH}$	-	0	5.0	µA	V_{IN} = 5.5 V, V_{SW} = 0 V, Ta = 25 °C
Low Side FET Leakage Current	$I_{LEAKSWL}$	-	0	5.0	µA	V_{IN} = 5.5 V, V_{SW} = 5.5 V, Ta = 25 °C
SW Current of Over Current Protection *(Note 2)*	I_{OCP}	0.8	1.2	1.6	A	
SCP, OVP						
Short Circuit Protection Detection Voltage	V_{SCP}	V_{OUT} x 0.6	V_{OUT} x 0.7	V_{OUT} x 0.8	V	V_{OUT} Falling
Output Over Voltage Protection Detection Voltage	V_{OVP}	V_{OUT} x 1.10	V_{OUT} x 1.15	V_{OUT} x 1.20	V	V_{OUT} Rising

(Note 1) It is tested in a proprietary test mode that connects VOUT to the output of the error amplifier.
(Note 2) This is design value. Not production tested.

Typical Performance Curves

Unless otherwise specified $V_{IN} = V_{EN}$

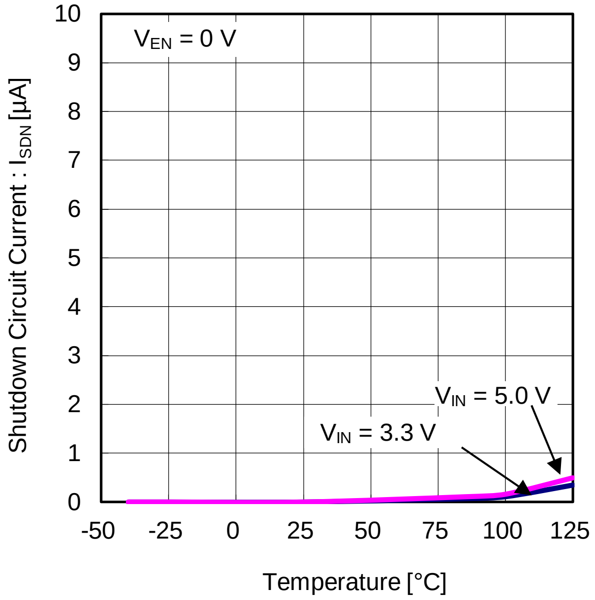


Figure 3. Shutdown Circuit Current vs Temperature

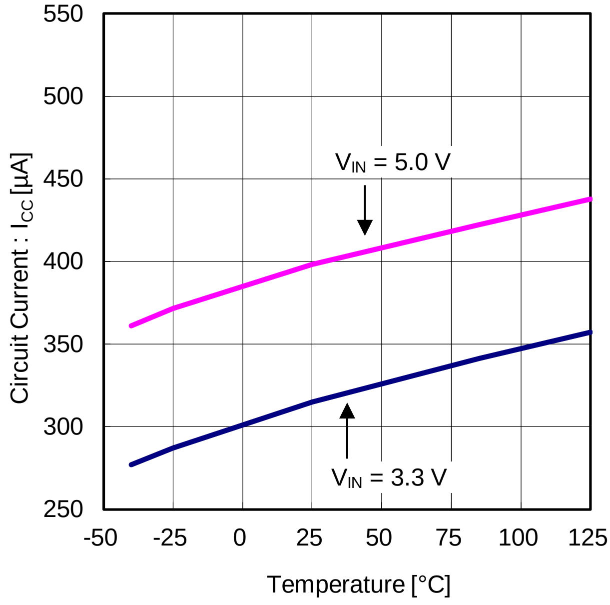


Figure 4. Circuit Current vs Temperature

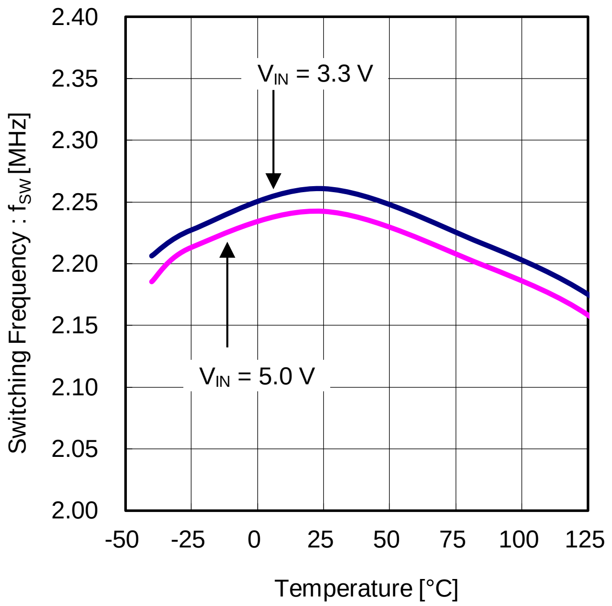


Figure 5. Switching Frequency vs Temperature

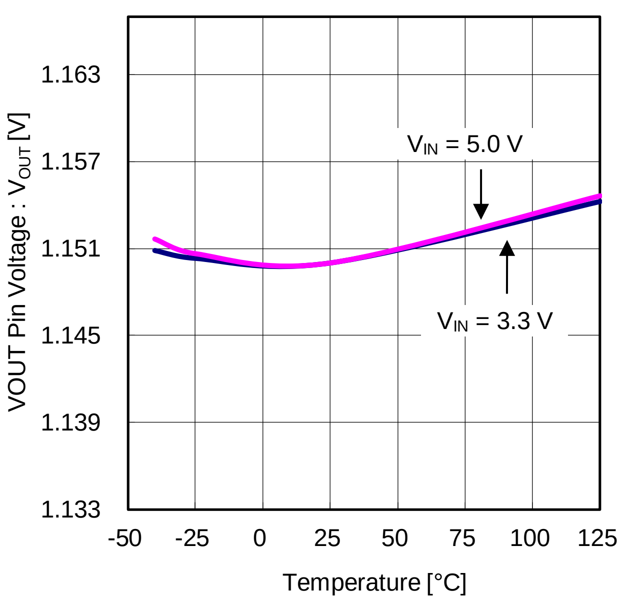


Figure 6. VOUT Pin Voltage vs Temperature

Typical Performance Curves – continued

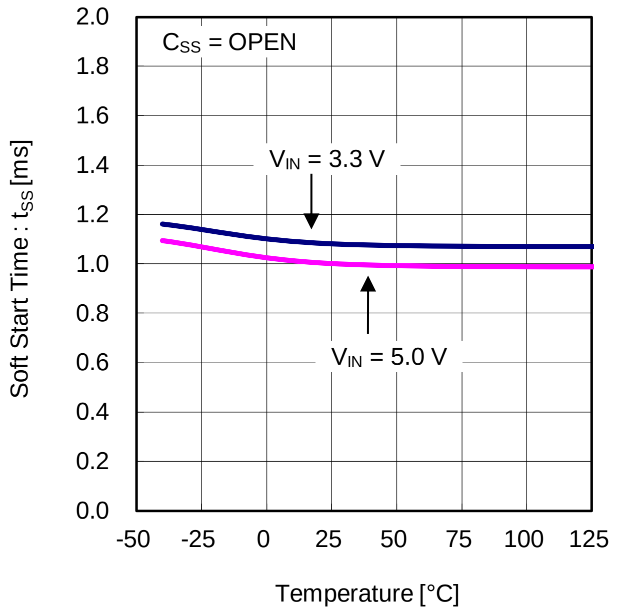


Figure 7. Soft Start Time vs Temperature

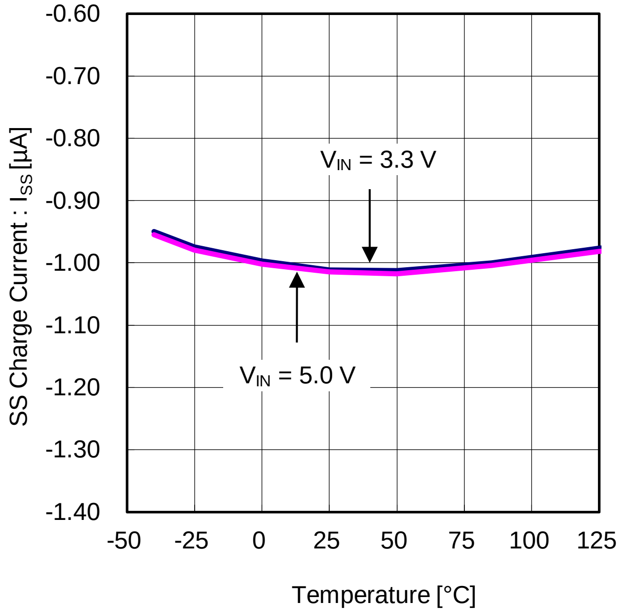


Figure 8. SS Charge Current vs Temperature

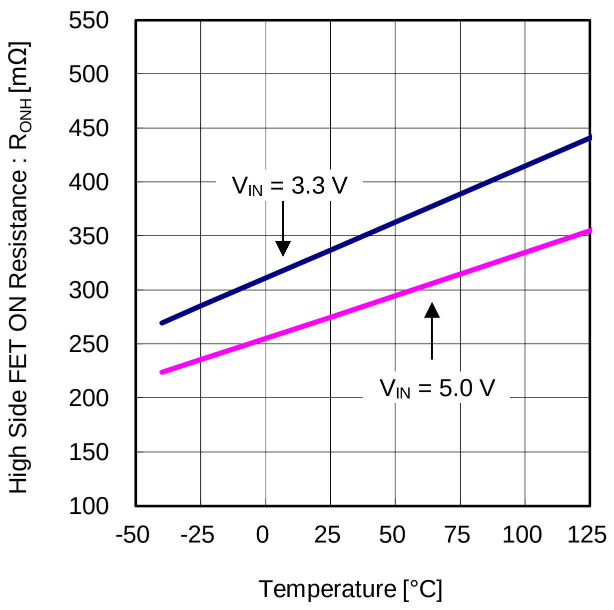


Figure 9. High Side FET ON Resistance vs Temperature

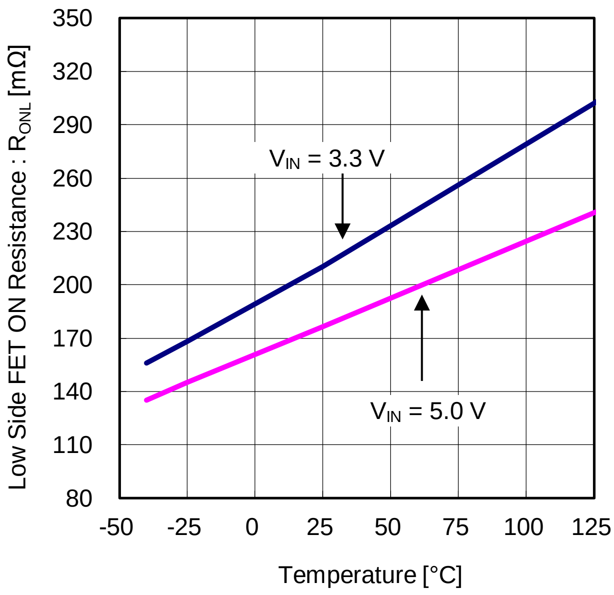


Figure 10. Low Side FET ON Resistance vs Temperature

Typical Performance Curves – continued

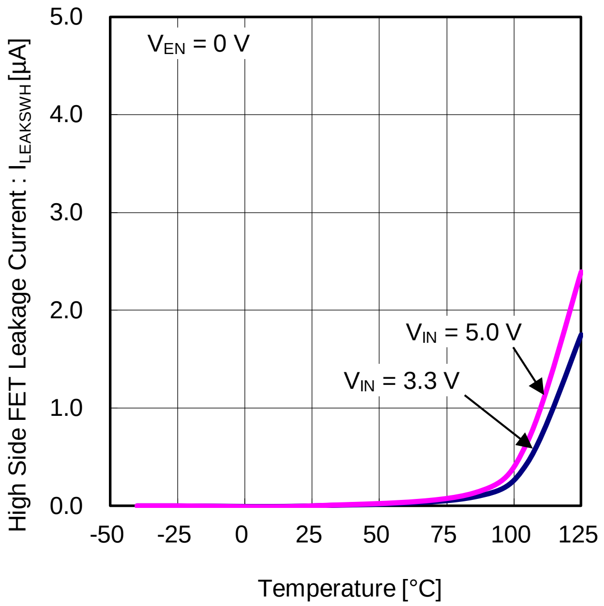


Figure 11. High Side FET Leakage Current vs Temperature

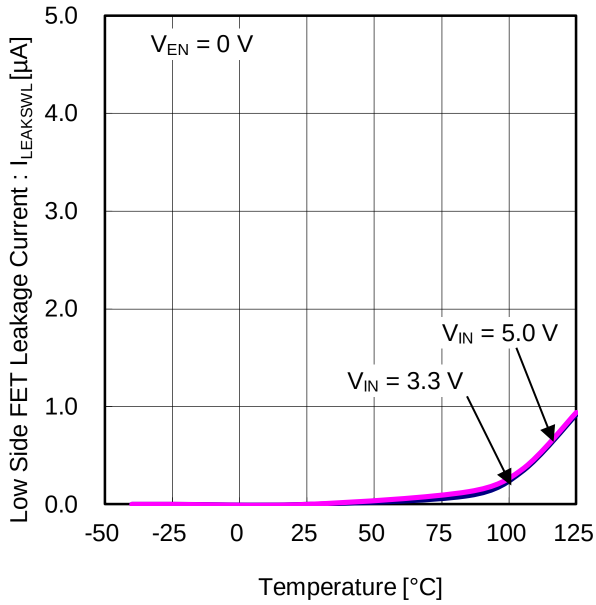


Figure 12. Low Side FET Leakage Current vs Temperature

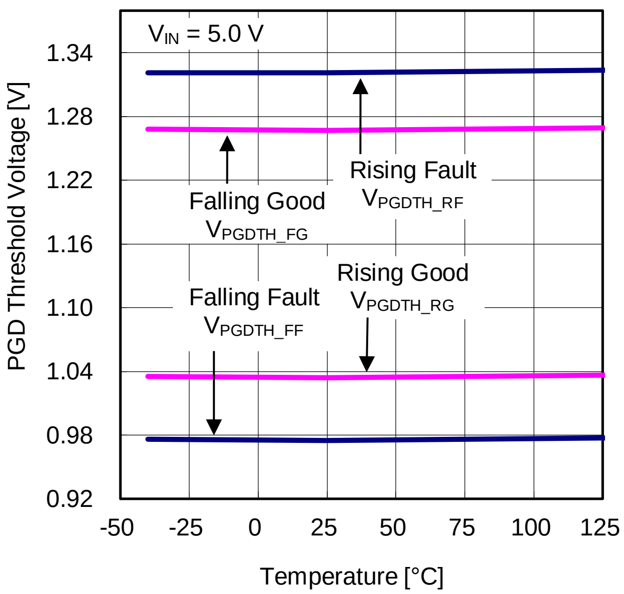


Figure 13. PGD Threshold Voltage vs Temperature

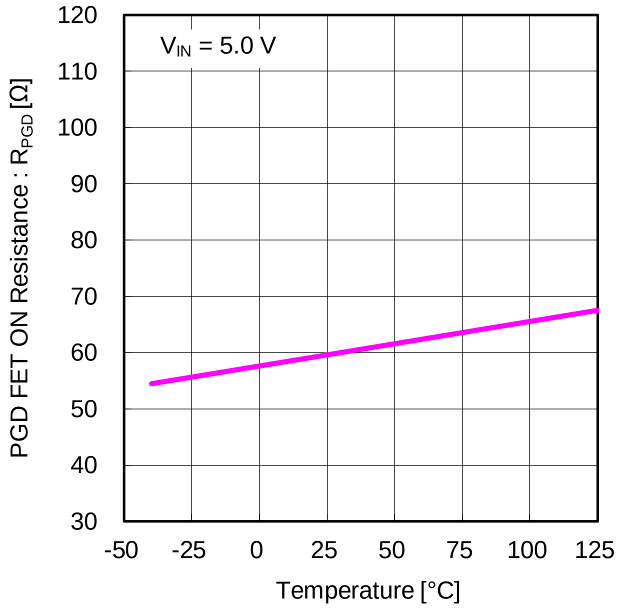


Figure 14. PGD FET ON Resistance vs Temperature

Typical Performance Curves – continued

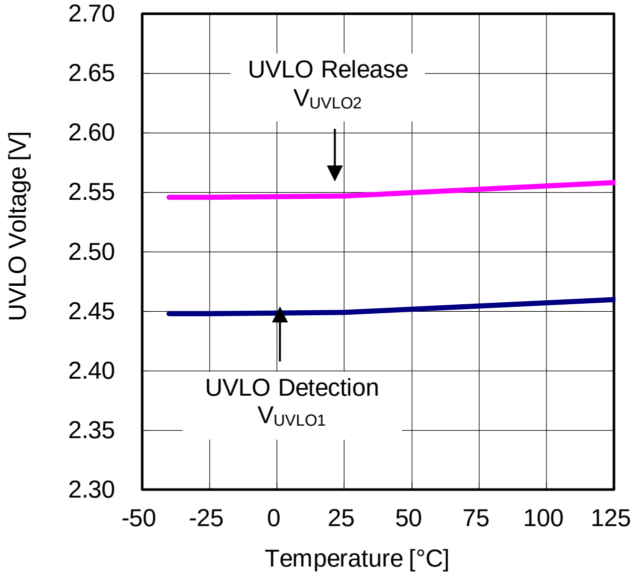


Figure 15. UVLO Voltage vs Temperature

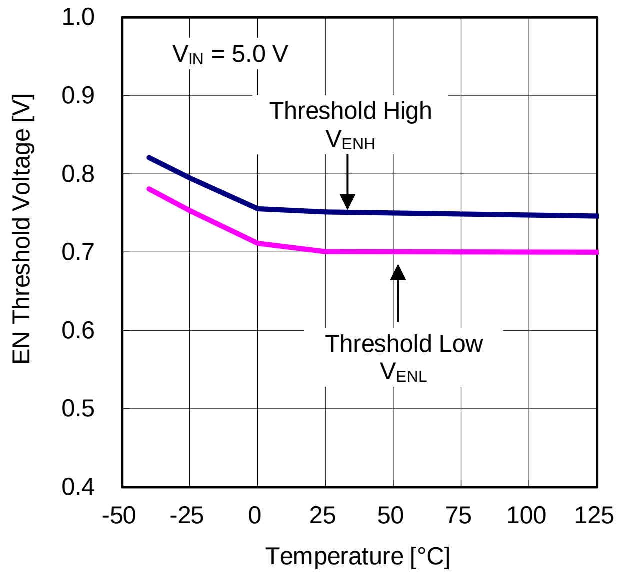


Figure 16. EN Threshold Voltage vs Temperature

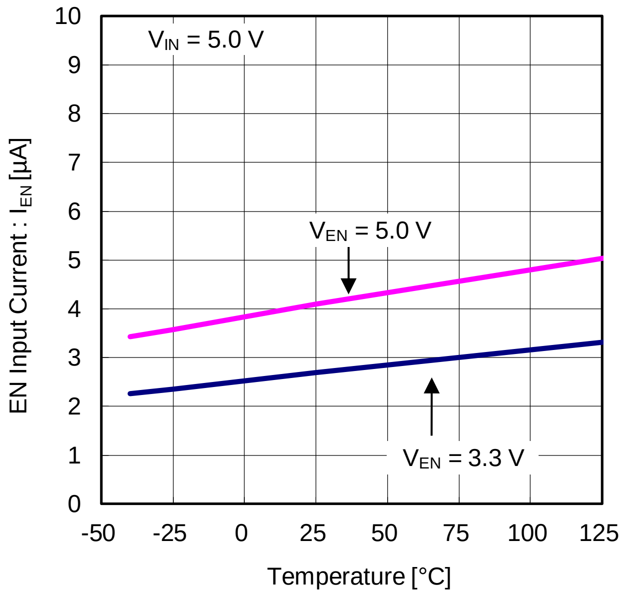


Figure 17. EN Input Current vs Temperature

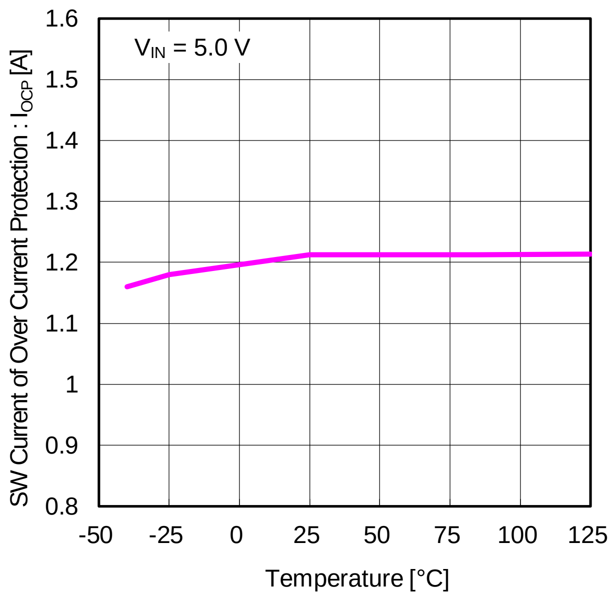


Figure 18. SW Current of Over Current Protection vs Temperature

Typical Performance Curves – continued

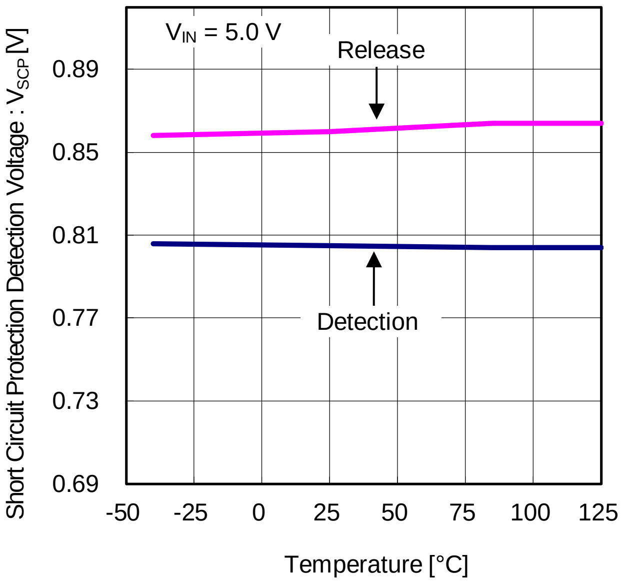


Figure 19. Short Circuit Protection Detection Voltage vs Temperature

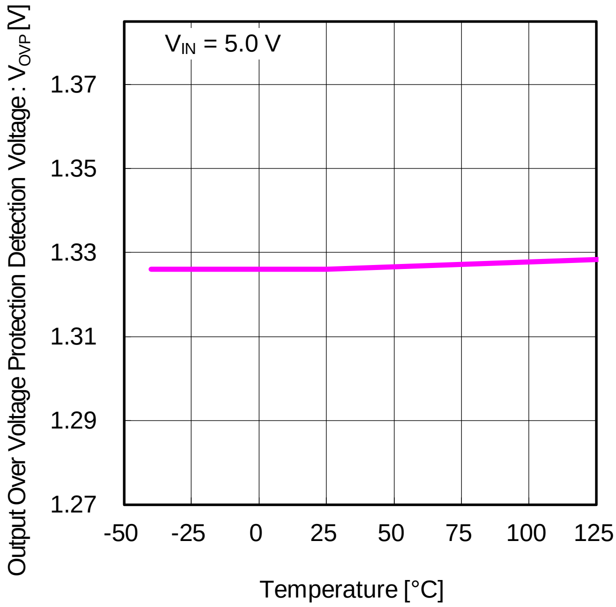


Figure 20. Output Over Voltage Protection Detection Voltage vs Temperature

Function Explanations

1. Enable Control

The device shutdown can be controlled by the voltage applied to the EN pin. When V_{EN} becomes 1.0 V or more, the internal circuit is activated and the device starts up with soft start. When V_{EN} becomes 0.4 V or less, the device is shutdown. The PGD output is enabled after soft start is completed.

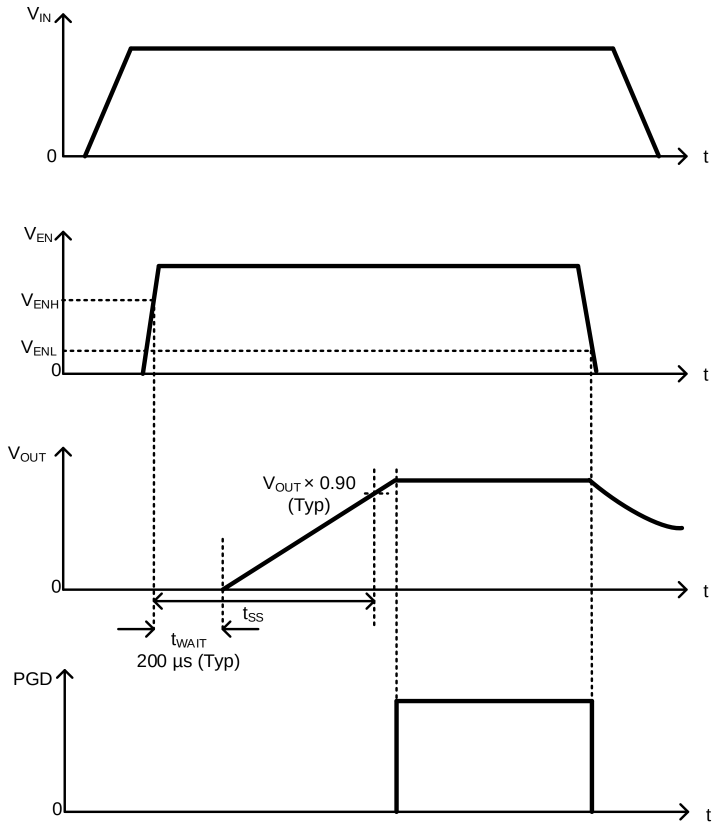


Figure 21. Enable ON/OFF Timing Chart (The SS Pin OPEN)

2. Power Good Function

When the VOUT pin voltage reaches within ±10 % (Typ) of the voltage setting, the PGD pin open drain MOSFET turns OFF and the output turns high. There is a 5 % hysteresis on the threshold voltage, so when the VOUT pin voltage reaches outside ±15 % (Typ) of the voltage setting, the PGD pin open drain MOSFET turns ON and the PGD pin is pulled down with impedance of 60 Ω (Typ). It is recommended to use a pull-up resistor of 2 kΩ to 100 kΩ for the power source. This function is enabled after soft start is completed.

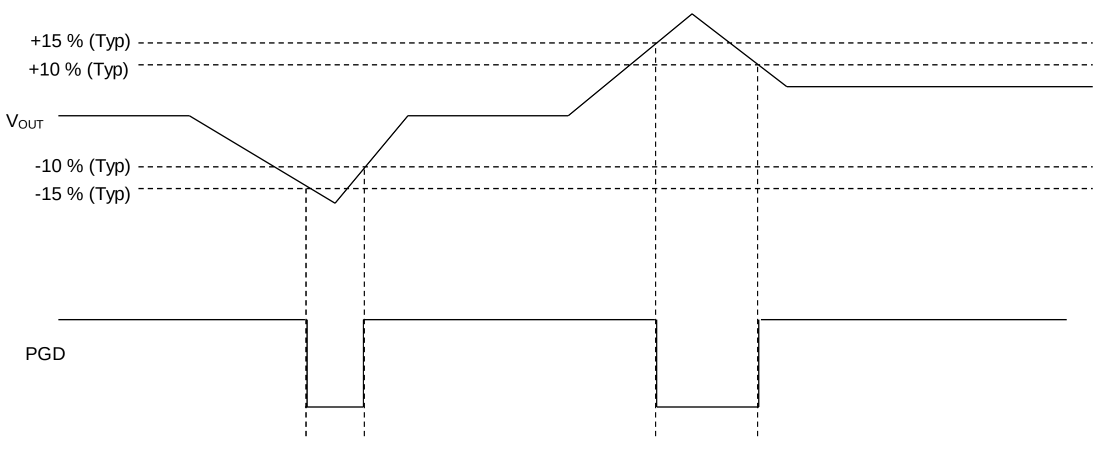


Figure 22. Power Good Timing Chart

Function Explanations – continued

3. Pre-bias Function

The device can start up without sinking a large current from output even if it is in the state of pre-biased. For example, if the device enabled during pre-biased condition, integrated MOSFETs keep OFF until internal SS voltage exceeds internal FB voltage by more than 40 mV (Typ). After that, the device starts switching and the output voltage increases with soft start. The PGD output is enabled after soft start is completed.

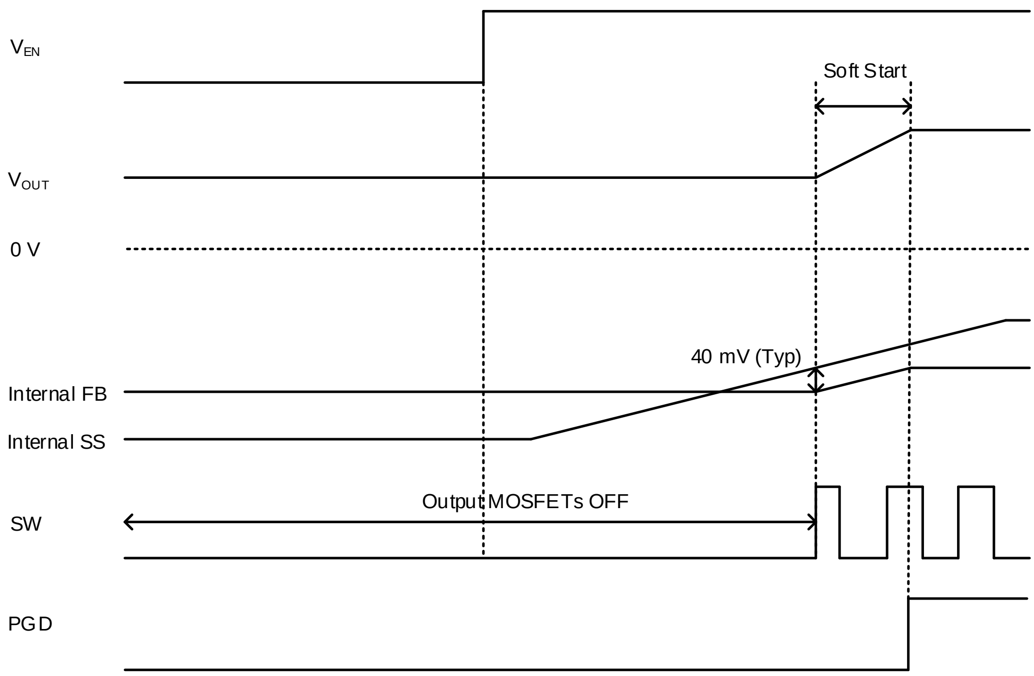


Figure 23. Pre-bias Start Up Timing Chart

Protection

1. Short Circuit Protection (SCP)

The Short Circuit Protection block compares the VOUT pin voltage with the internal reference voltage VREF. When the VOUT pin voltage has fallen to 70 % (Typ) of the voltage setting or less and remained there for 1 ms (Typ), SCP stops the operation for 14 ms (Typ) and subsequently initiates a restart. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the device should not be used in applications characterized by continuous operation of the protection circuit (e.g. when a load that significantly exceeds the output current capability of the chip is connected at all times).

The EN Pin	The VOUT Pin	Short Circuit Protection	Short Circuit Protection Operation
1.0 V or higher	≤ V_{OUT} x 0.7 (Typ)	Enabled	ON
	≥ V_{OUT} x 0.75 (Typ)		OFF
0.4 V or lower	-	Disabled	OFF

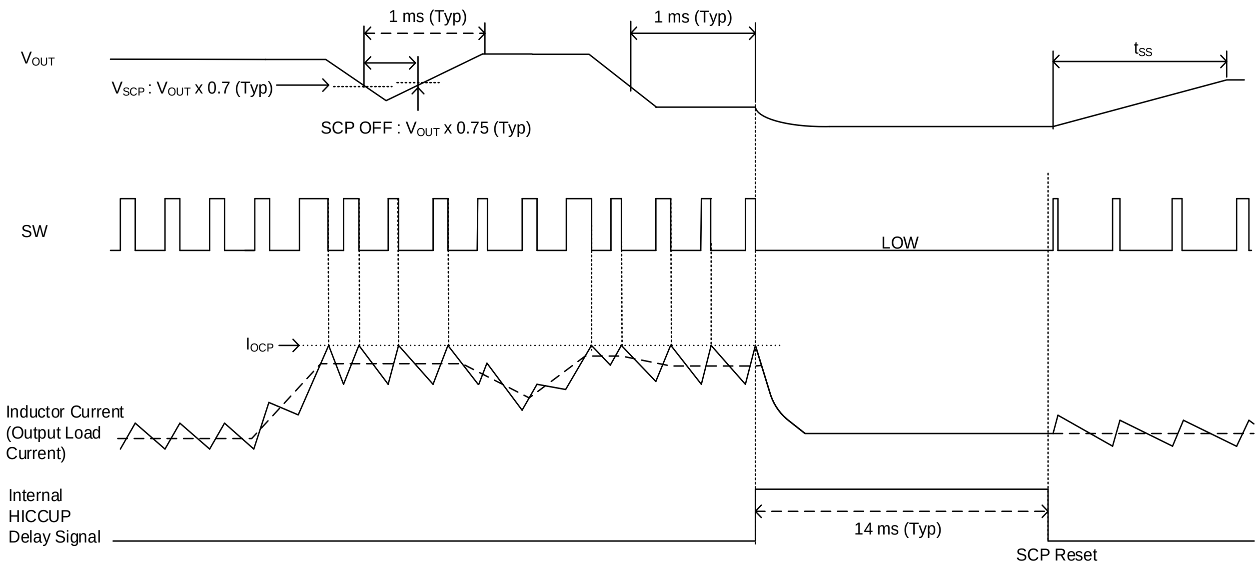


Figure 24. SCP Timing Chart

2. Over Current Protection (OCP)

The Over Current Protection function operates by limiting the current that flows through High Side FET at each cycle of the switching frequency. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the device should not be used in applications characterized by continuous operation of the protection circuit (e.g. when a load that significantly exceeds the output current capability of the chip is connected at all times).

Protection – continued

3. Under Voltage Lockout Protection (UVLO)

It shuts down the device when the VIN pin falls to 2.45 V (Typ) or lower.
The threshold voltage has a hysteresis of 100 mV (Typ).

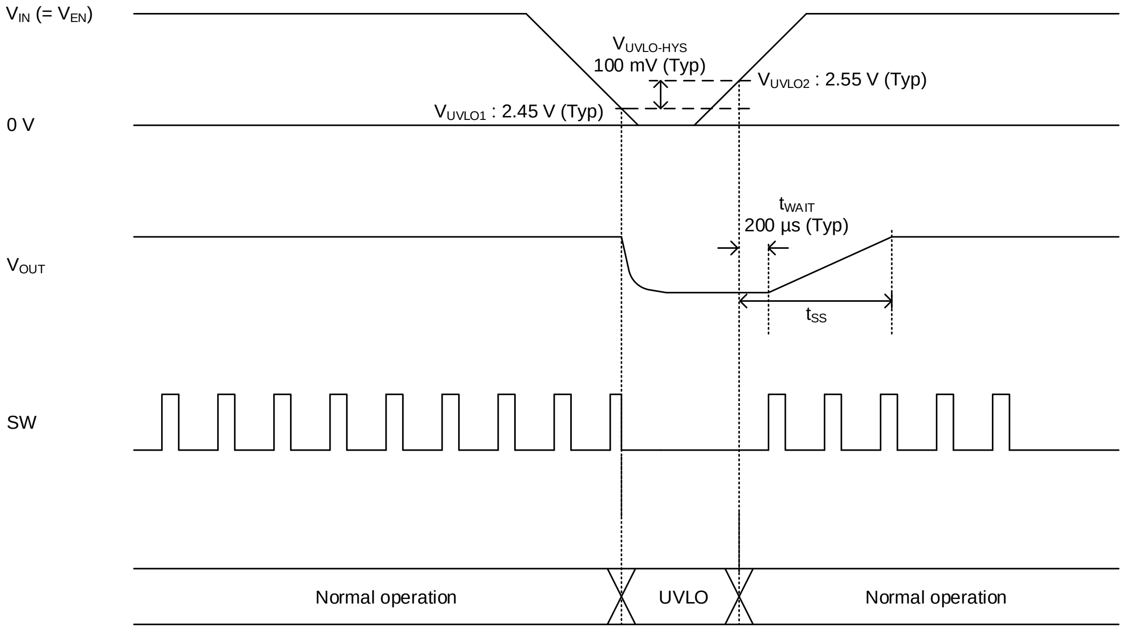


Figure 25. UVLO Timing Chart

4. Thermal Shutdown (TSD)

This is the thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. However, if the rating is exceeded for a continued period and the junction temperature (Tj) rises to 175 °C (Typ), the TSD circuit activates and the output MOSFETs turns OFF. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation. Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

5. Over Voltage Protection (OVP)

The device incorporates an over voltage protection circuit to minimize the output voltage overshoot when recovering from strong load transients or output fault conditions. If the VOUT pin voltage becomes over or equal to +15 % (Typ) of the voltage setting, which is Output Over Voltage Protection Detection Voltage, the MOSFETs on the output stage is turned OFF to prevent the increase in the output voltage. After the detection, the switching operation resumes if the output decreases and the over voltage state is released. Output Over Voltage Protection Detection Voltage and release voltage have a hysteresis of 5 %.

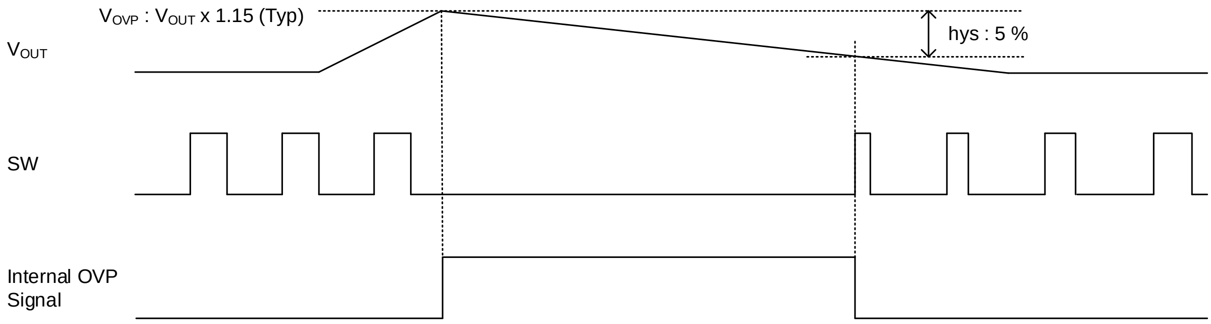


Figure 26. OVP Timing Chart

Selection of Components Externally Connected

Contact us if not use the recommended constant in this section.

Necessary parameters in designing the power supply are as follows:

Table 1. Application Specification

Parameter	Symbol	Example Value
Input Voltage	V_{IN}	5.0 V
Output Voltage	V_{OUT}	1.15 V (Typ)
Switching Frequency	f_{SW}	2.2 MHz (Typ)
Output Capacitor	C_{OUT}	10 µF
Soft Start Time	t_{SS}	8.0 ms (Typ)
Maximum Output Current	I_{OUTMAX}	600 mA

Application Example

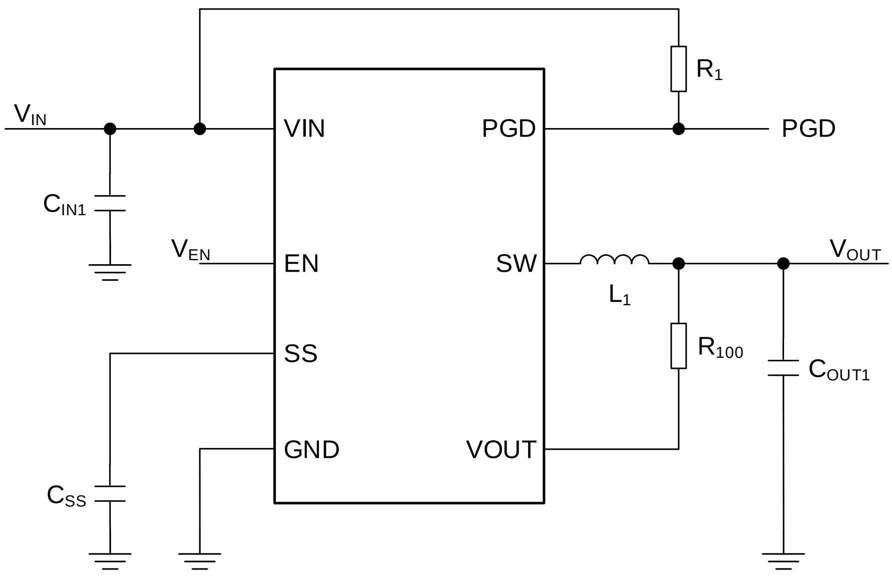


Figure 27. Typical Application

1. **Switching Frequency**
The switching frequency f_{SW} is fixed at 2.2 MHz (Typ) inside the IC.

2. **Selection of Input Capacitor**
Use ceramic type capacitor for the input capacitor C_{IN1}. C_{IN1} is used to suppress the input ripple noise and this capacitor is effective by being placed as close as possible to the VIN pin. Set the capacitor value for C_{IN1} so that it does not fall to 4.7 µF considering the capacitor value variances, temperature characteristics, DC bias characteristics, aging characteristics, and etc. Use components which are comparatively same with the components used in "Application Example" on page 19. Moreover, factors like the PCB layout and the position of the capacitor may lead to IC malfunction. Refer to "PCB layout Design" on page 21 and 22.
In addition, the capacitor with value 0.1 µF can be added to suppress the high frequency noise as an option.

Selection of Components Externally Connected – continued

3. Selection of Output LC Filter

In order to supply a continuous current to the load, the DC/DC converter requires an LC filter for smoothing the output voltage. Use the inductor with value 1.0 µH to 2.2 µH.

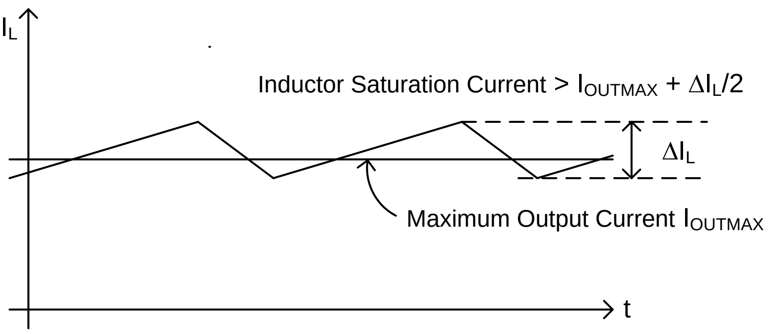


Figure 28. Waveform of Current through Inductor

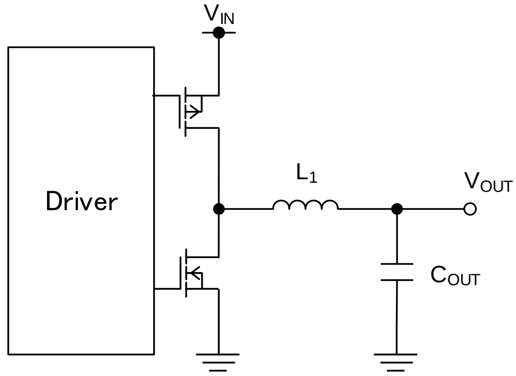


Figure 29. Output LC Filter Circuit

Inductor ripple current ΔI_L can be represented by the following equation.

$$\Delta I_L = V_{OUT} \times (V_{IN} - V_{OUT}) \times \frac{1}{V_{IN} \times f_{SW} \times L_1} = 268 \text{ [mA]}$$

where

V_{IN} is the 5.0 V

V_{OUT} is the 1.15 V

L_1 is the 1.5 µH

f_{SW} is the 2.2 MHz (Switching Frequency)

The rated current of the inductor must be larger than the sum of the maximum output current and 1/2 of the inductor ripple current ΔI_L.

Use ceramic type capacitor for the output capacitor C_{OUT}. The capacitance value of C_{OUT} is recommended in the range between 10 µF and 22 µF. C_{OUT} affects the output ripple voltage characteristics. C_{OUT} must satisfy the required ripple voltage characteristics.

The output ripple voltage can be represented by the following equation.

$$\Delta V_{RPL} = \Delta I_L \times \left(R_{ESR} + \frac{1}{8 \times C_{OUT} \times f_{SW}}\right) \text{ [V]}$$

Where

R_{ESR} is the Equivalent Series Resistance (ESR) of the output capacitor

The output ripple voltage ΔV_{RPL} can be represented by the following equation.

$$\Delta V_{RPL} = 0.268\ A \times \left(10\ m\Omega + \frac{1}{8 \times 10\ \mu F \times 2.2\ MHz}\right) = 4.20 \text{ [mV]}$$

where

C_{OUT} is the 10 µF

R_{ESR} is the 10 mΩ

Stable transient response and the loop is dependent to C_{OUT}. Actually, characteristics vary depending on PCB layout, arrangement of wiring, kinds of parts used and use conditions (temperature, etc.). Please be sure to check stability and responsiveness with the actual application.

4. Selection of Soft Start Capacitor

Turning the EN pin signal high activates the soft start function. This causes the output voltage to rise gradually while the current at startup is placed under control. This allows the prevention of output voltage overshoot and inrush current. The rise time t_{SS_EXT} depends on the value of the capacitor connected to the SS pin. The capacitance value should be set in the range between 4700 pF and 0.082 µF.

$$t_{SS\_EXT} = \frac{(C_{SS} \times 0.8)}{I_{SS}} \ \text{[s]}$$

$$t_{OFFSET} = \frac{(C_{SS} \times 0.04)}{I_{SS}} \ \text{[s]}$$

where

t_{SS_EXT} is the Soft Start Time
t_{OFFSET} is the Internal Delay Time
C_{SS} is the Capacitor connected to the SS pin
I_{SS} is the SS Charge Current 1.0 µA (Typ)

With C_{SS} = 0.01 µF

$$t_{SS\_EXT} = \frac{(0.01\ \mu F \times 0.8)}{1.0\ \mu A} = 8.0 \ \text{[ms]}$$

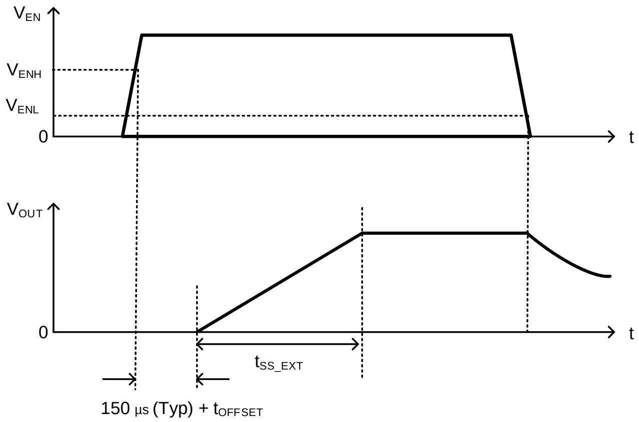


Figure 30. Soft Start Timing Chart

Turning the EN pin High without connecting capacitor to the SS pin and keeping the SS pin either OPEN condition or 10 kΩ to 100 kΩ pull up condition to power source, the output rises in 1 ms (Typ).

Recommended Parts Manufacturer List

Shown below is the list of the recommended parts manufacturers for reference.

Table 2

Type	Manufacturer	URL
Ceramic capacitors	Murata	www.murata.com
Ceramic capacitors	TDK	product.tdk.com
Inductors	Coilcraft	www.coilcraft.com
Inductors	Cyntec	www.cyntec.com
Inductors	Murata	www.murata.com
Inductors	Sumida	www.sumida.com
Inductors	TDK	product.tdk.com
Resistors	ROHM	www.rohm.com

Application Example

Table 3. Specification Example

Parameter	Symbol	Example Value
Product Name	IC	BD9SD11NUX-C
Supply Voltage	V_{IN}	5.0 V, 3.3 V
Output Voltage	V_{OUT}	1.15 V (Typ)
Soft Start Time	t_{SS}	1.0 ms (Typ)
Maximum Output Current	I_{OUTMAX}	600 mA
Operation Temperature Range	Ta	-40 °C to +125 °C

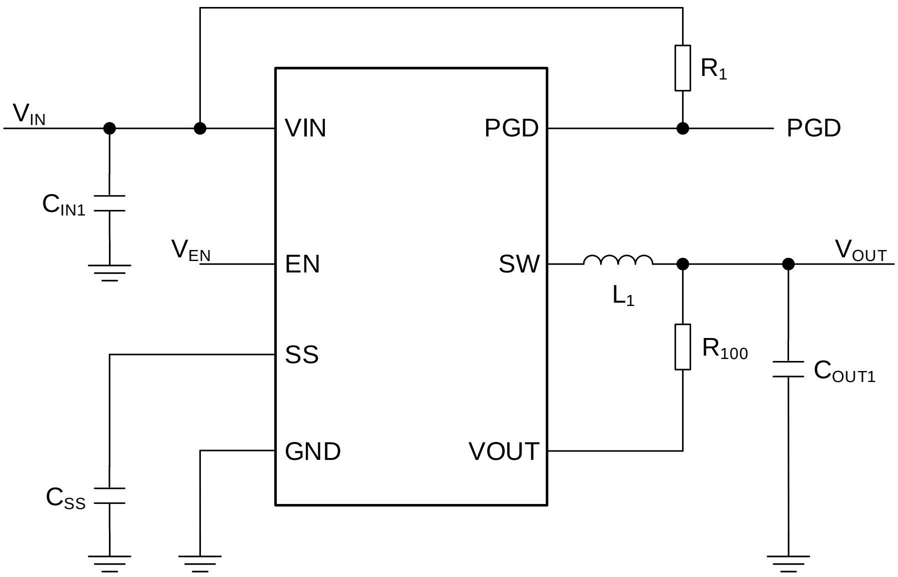


Figure 31. Reference Circuit

Table 4. Parts List

No	Package	Parameters	Part Name (Series)	Type	Manufacturer
L_1	2016	1.5 µH	TFM201610ALMA1R5M	Inductor	TDK
C_{OUT1}	2012	10 µF, X7R, 6.3 V	GCM21BR70J106K	Ceramic Capacitor	Murata
C_{IN1}	2012	10 µF, X7R, 10 V	GCM21BR71A106K	Ceramic Capacitor	Murata
R_{100}	-	SHORT	-	-	-
R_1	1005	100 kΩ, 1 %, 1/16 W	MCR01MZPF1003	Chip Resistor	ROHM
C_{SS}	-	-	-	-	-

Characteristic Data (Application Examples)

$V_{IN} = V_{EN}$, Ta = 25 °C

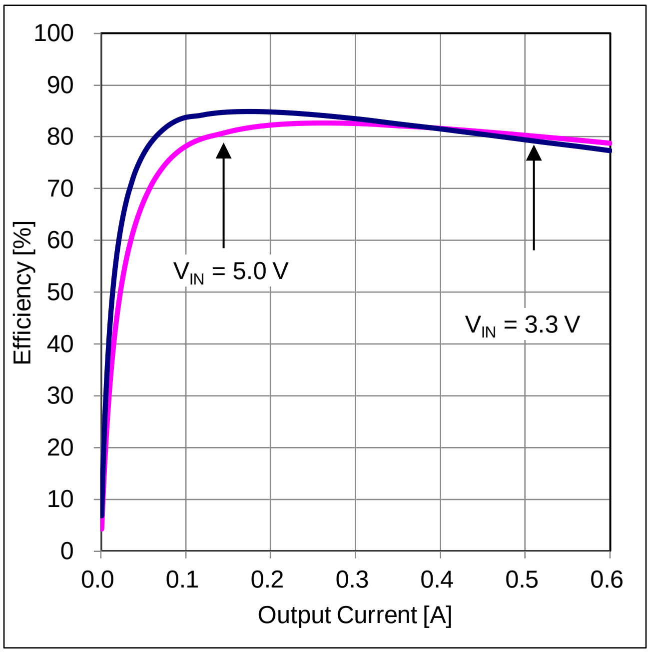


Figure 32. Efficiency vs Output Current

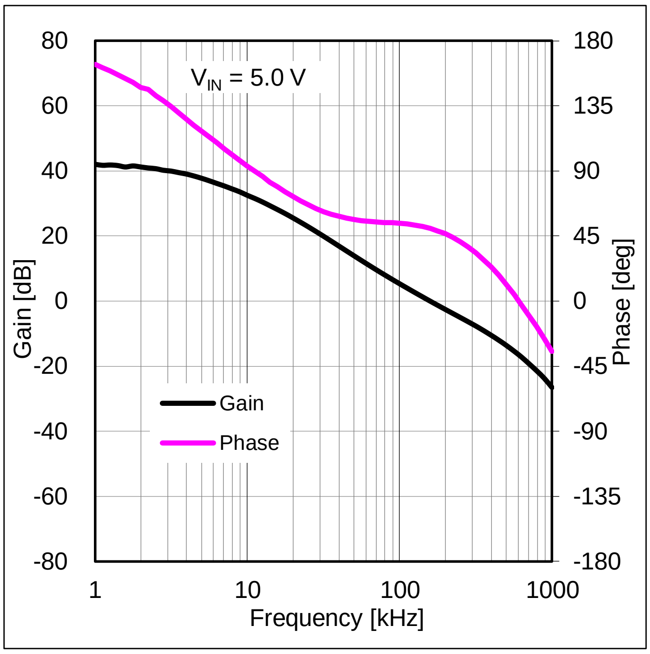


Figure 33. Frequency Characteristics
(I_{OUT} = 0.6 A)

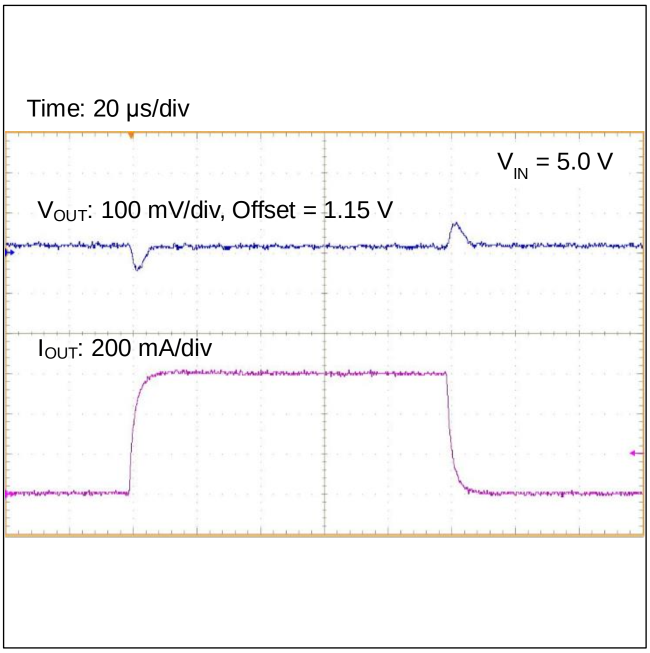


Figure 34. Load Transient Response
(I_{OUT} = 0 A ↔ 0.6 A)

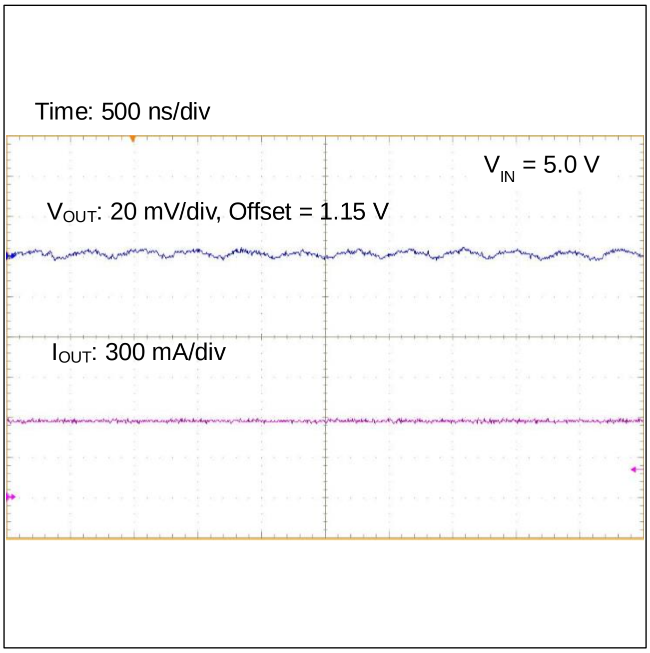


Figure 35. Output Ripple Voltage
(I_{OUT} = 0.6 A)

PCB Layout Design

PCB layout design for DC/DC converter is very important. Appropriate layout can avoid various problems concerning power supply circuit. Figure 36 to 38 show the current path in a buck DC/DC converter circuit. The Loop 1 in Figure 36 is a current path when H-side Switch is ON and L-side Switch is OFF, the Loop 2 in Figure 37 is when H-side Switch is OFF and L-side Switch is ON. The thick line in Figure 38 shows the difference between Loop1 and Loop2. The current in thick line change sharply each time the switching element H-side and L-side FET change from OFF to ON, and vice versa. These sharp changes induce a waveform with harmonics in this loop. Therefore, the loop area of thick line that is consisted by input capacitor and IC should be as small as possible to minimize noise. For more details, refer to application note of switching regulator series “PCB Layout Techniques of Buck Converter”.

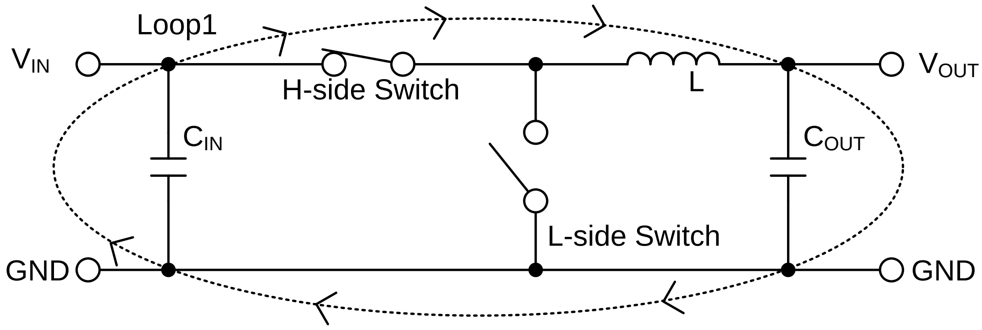


Figure 36. Current Path when H-side Switch = ON, L-side Switch = OFF

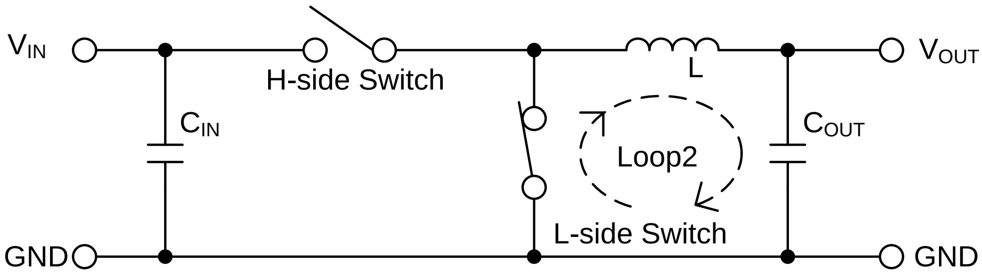


Figure 37. Current Path when H-side Switch = OFF, L-side Switch = ON

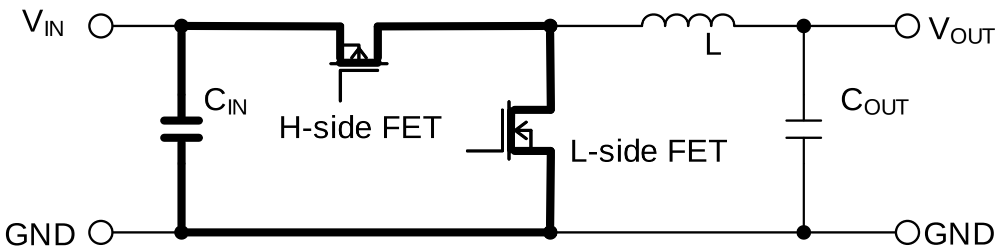
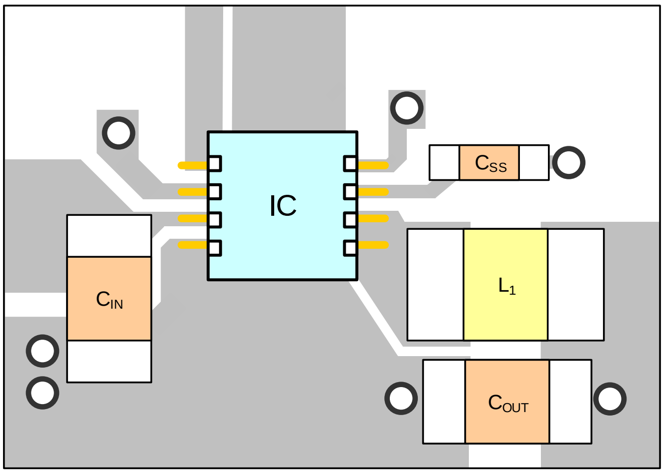


Figure 38. Difference of Current and Critical Area in PCB Layout

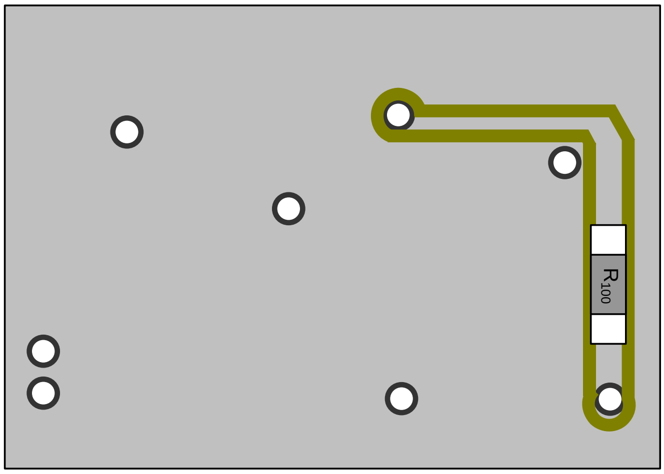
PCB Layout Design – continued

When designing the PCB layout, please pay extra attention to the following points:

- Connect the input capacitor C_{IN} as close as possible to the VIN pin and GND pin on the same plane as the IC.
- Switching nodes such as SW are susceptible to noise due to AC coupling with other nodes. Route the inductor pattern as thick and as short as possible.
- Feedback line connected to VOUT pin far from the SW nodes.
- R_{100} is provided for the measurement of feedback frequency characteristics (optional). By inserting a resistor into R_{100}, it is possible to measure the frequency characteristics of feedback (phase margin) using FRA etc. R_{100} is short-circuited for normal use.



Example of Evaluation Board Layout (Top View)



Example of Evaluation Board Layout (Bottom View)

Figure 39. Example of Evaluation Board Layout

Power Dissipation

For thermal design, be sure to operate the IC within the following conditions.
(Since the temperatures described hereunder are all guaranteed temperatures, take margin into account.)

1. The ambient temperature Ta is to be 125 °C or less.
2. The chip junction temperature Tj is to be 150 °C or less.

The chip junction temperature Tj can be considered in the following two patterns:

1. To obtain Tj from the package surface center temperature Tt in actual use

$$Tj = Tt + \psi_{JT} \times W \quad [°C]$$

2. To obtain Tj from the ambient temperature Ta

$$Tj = Ta + \theta_{JA} \times W \quad [°C]$$

Where:

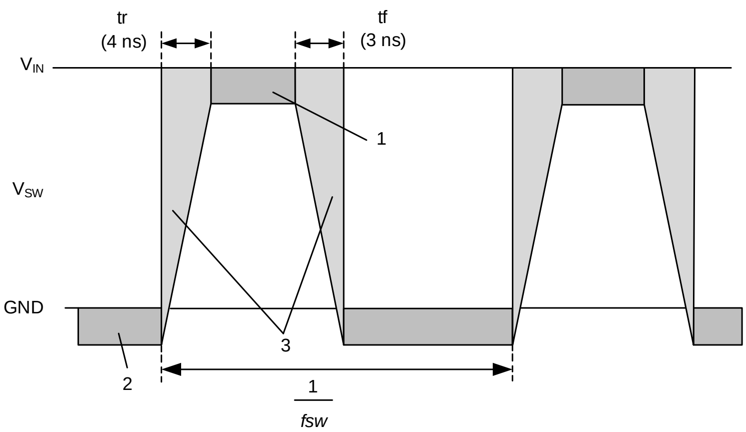
ψ_{JT}	is junction to top characterization parameter (Refer to page 5)
θ_{JA}	is junction to ambient (Refer to page 5)

The heat loss W of the IC can be obtained by the formula shown below:

$$W = R_{ONH} \times {I_{OUT}}^2 \times \frac{V_{OUT}}{V_{IN}} + R_{ONL} \times {I_{OUT}}^2 \left(1 - \frac{V_{OUT}}{V_{IN}}\right) + V_{IN} \times I_{CC} + \frac{1}{2} \times (tr + tf) \times V_{IN} \times I_{OUT} \times f_{SW} \quad [W]$$

Where:

R_{ONH}	is the High Side FET ON Resistance (Refer to page 6) [Ω]
R_{ONL}	is the Low Side FET ON Resistance (Refer to page 6) [Ω]
I_{OUT}	is the Output Current [A]
V_{OUT}	is the Output Voltage [V]
V_{IN}	is the Input Voltage [V]
I_{CC}	is the Circuit Current (Refer to page 6) [A]
tr	is the Switching Rise Time [s] (Typ:4 ns)
tf	is the Switching Fall Time [s] (Typ:3 ns)
f_{SW}	is the Switching Frequency (Refer to page 6) [Hz]

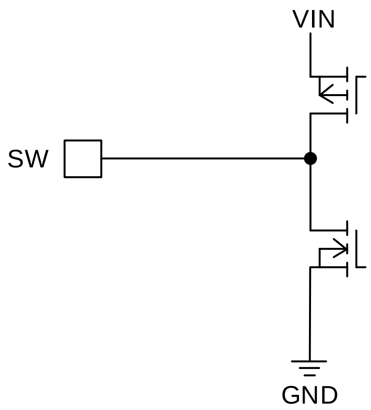


1. $R_{ONH} \times {I_{OUT}}^2$
2. $R_{ONL} \times {I_{OUT}}^2$
3. $\frac{1}{2} \times (tr + tf) \times V_{IN} \times I_{OUT} \times f_{SW}$

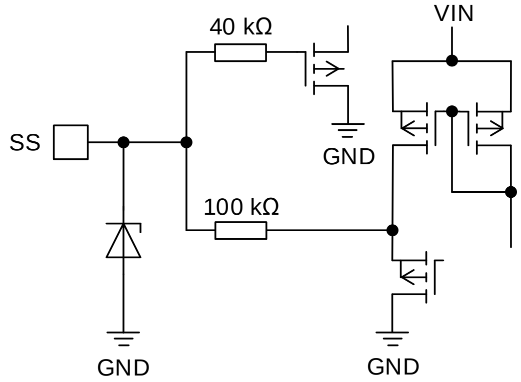
Figure 40. SW Waveform

I/O Equivalence Circuits (Note 1)

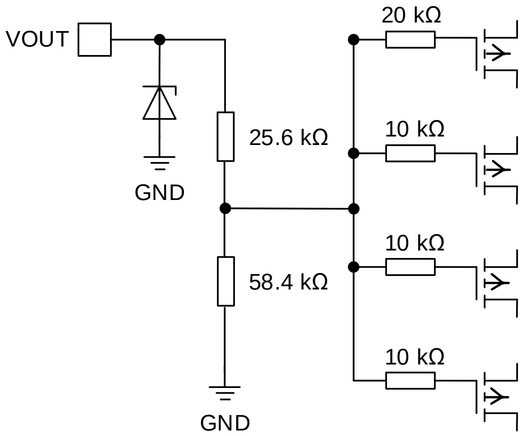
1. 2. SW



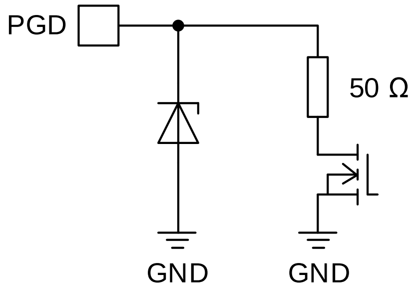
3. SS



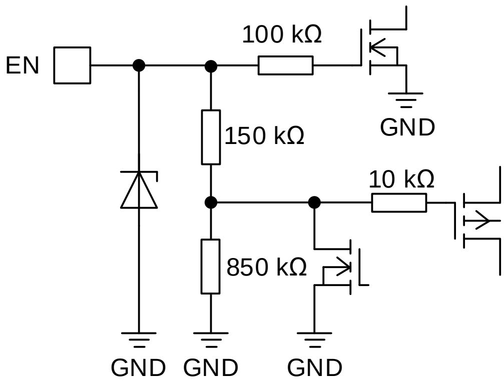
4. VOUT



5. PGD



6. EN



(Note 1) Resistance value is Typical.

Operational Notes

1. **Reverse Connection of Power Supply**
Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. **Power Supply Lines**
Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. **Ground Voltage**
Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition. However, pins that drive inductive loads (e.g. motor driver outputs, DC-DC converter outputs) may inevitably go below ground due to back EMF or electromotive force. In such cases, the user should make sure that such voltages going below ground will not cause the IC and the system to malfunction by examining carefully all relevant factors and conditions such as motor characteristics, supply voltage, operating frequency and PCB wiring to name a few.

4. **Ground Wiring Pattern**
When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. **Recommended Operating Conditions**
The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. **Inrush Current**
When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. **Testing on Application Boards**
When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. **Inter-pin Short and Mounting Errors**
Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. **Unused Input Pins**
Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.
When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

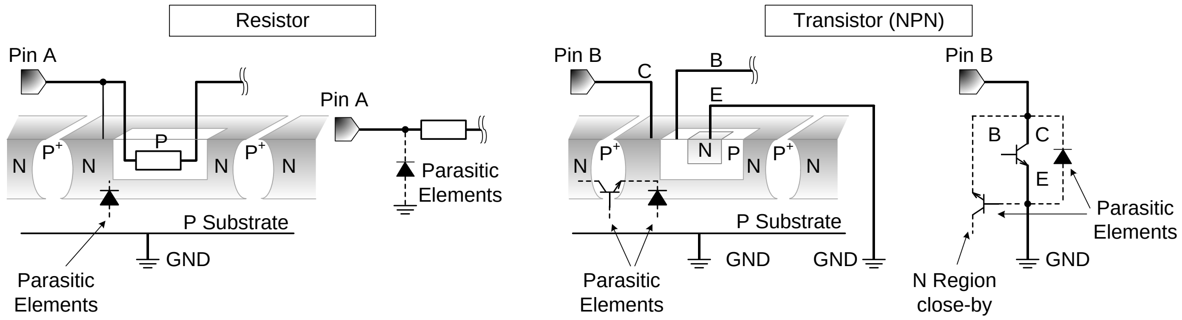


Figure 41. Example of Monolithic IC Structure

11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

12. Thermal Shutdown Circuit (TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

13. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

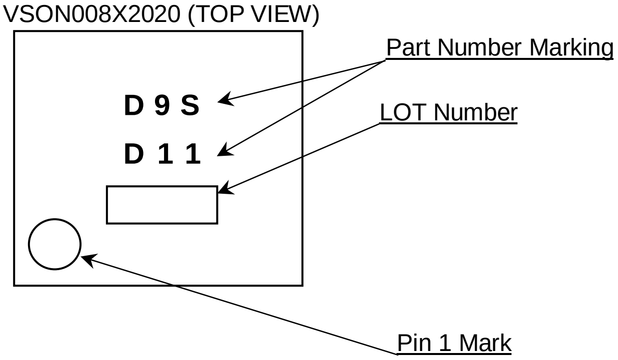
Ordering Information

B D 9 S D 1 1 N U X - C E 2

- Part Number: BD9SD11
- Package: NUX — VSON008X2020
- Product class: C for Automotive applications
- Packaging and forming specification: E2: Embossed tape and reel

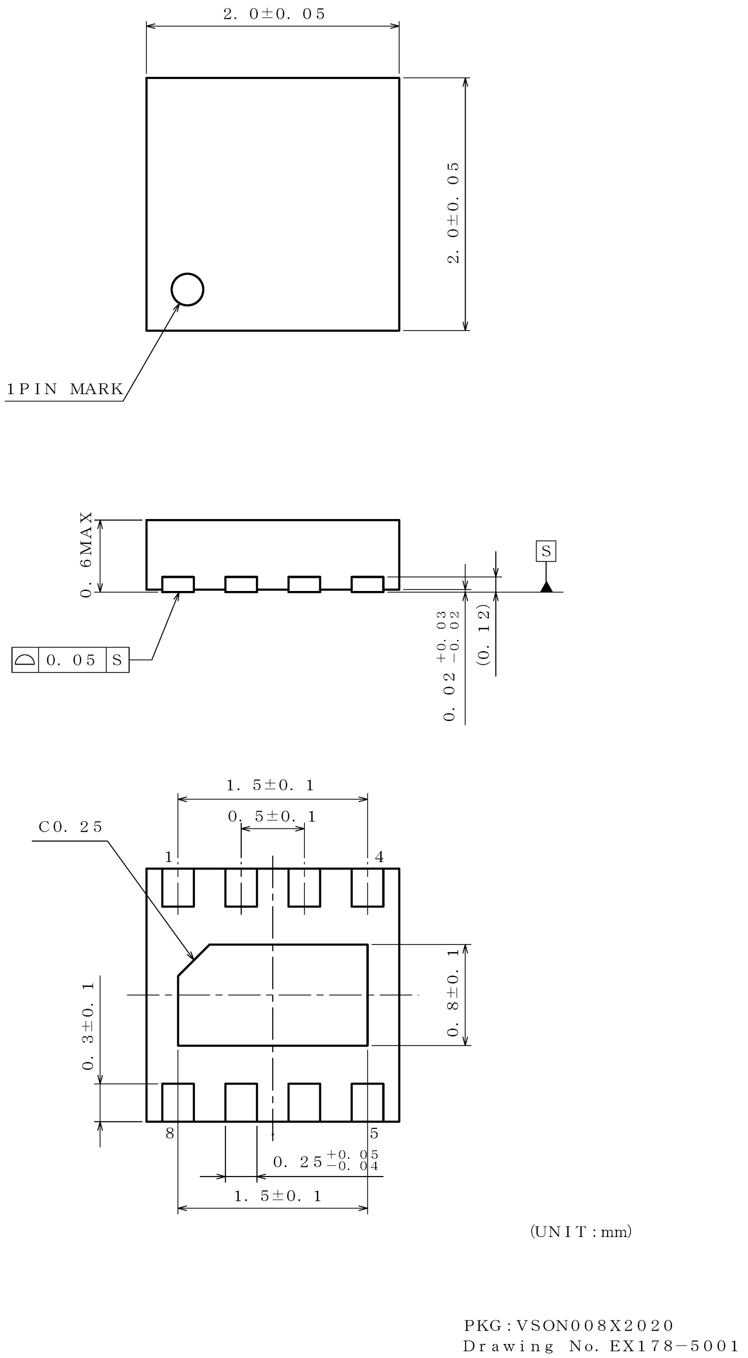
Marking Diagram

VSON008X2020 (TOP VIEW)



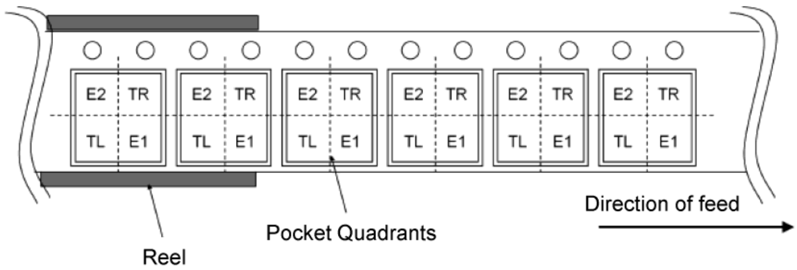
Physical Dimension and Packing Information

Package Name	VSON008X2020



< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	4000pcs
Direction of feed	E2 The direction is the pin 1 of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand



Revision History

Date	Revision	Changes
25.Feb.2020	001	New Release

Notice

Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   [a] Installation of protection circuits or other protective devices to improve system safety
   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   [a] the Products are exposed to sea winds or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [b] the temperature or humidity exceeds those recommended by ROHM
   [c] the Products are exposed to direct sunshine or condensation
   [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

Precaution Regarding Intellectual Property Rights

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